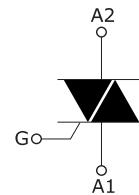


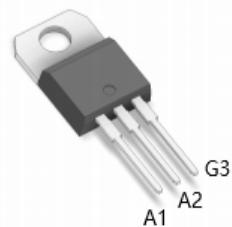
### Product features and main applications:

NPNPN five-layer structure of silicon bidirectional devices; with independent intellectual property rights of single-sided digging technology, table glass passivation process; multi-layer metallized electrodes on the back; with high blocking voltage and high temperature stability.



### Mainly used in:

vacuum cleaners, power tools and other motor speed controllers; solid state relays; heating controllers (temperature regulation); other phase control circuits.



TO-220A

## Characteristics

**Table 1. Absolute maximum ratings ( $T_j = 25^\circ\text{C}$  unless otherwise stated)**

Symbol	Parameter name	value	Unit
$I_{T(\text{RMS})}$	RMS on-state current (full sine wave)	24	A
$I_{TSM}$	Non repetitive surge peak on-state current (full cycle, $T_j$ initial = 25 °C)	240	A
$I^2t$	$I^2t$ value for fusing	288	$\text{A}^2\text{s}$
$di/dt$	Critical rate of rise of on-state current $IG = 2 \times IGT$ , $tr \leq 100 \text{ ns}$	50	$\text{A}/\mu\text{s}$

$V_{DRM}/V_{RRM}$	Off state repetitive peak voltage Reverse repetitive peak voltage	$T_j=25^\circ C$		800	V
$I_{GM}$	Peak gate current	$t_p=20\mu s$	$T_j=150^\circ C$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j=150^\circ C$	1	W
$T_{stg}$ $T_j$	Storage junction temperature range Operating junction temperature range		$-40 \text{ to } +150$ $-40 \text{ to } +125$		$^\circ C$

**Table 2. Electrical characteristics ( $T_j = 25^\circ C$ , unless otherwise specified)**  
--3quadrants

Symbol	Name and test conditions	Quadrant	Range	value		Unit	
$I_{GT}$	$V_D=12V$ $R_L=100\Omega$	I II III	MAX	$\leq 50$		mA	
$V_{GT}$			MAX	1.5		V	
$V_{GD}$			MIN	0.2		V	
$I_H$	$I_T = 100\text{ mA}$		MAX	80		mA	
$I_L$	$I_G = 1.2 \times I_{GT}$		MAX	I -III	80	mA	
				II	100		
$dv/dt$	VD = 67% VDRM, gate open, $T_j = 125^\circ C$	MIN	500			V/us	
$(dv/dt)_c$	Critical rise rate of commutation voltage $T_j = 150^\circ C$	MIN	10			V/us	

**Table 3. Electrical characteristics ( $T_j = 25^\circ\text{C}$ , unless otherwise specified) -Standard Triac (4 quadrants)**

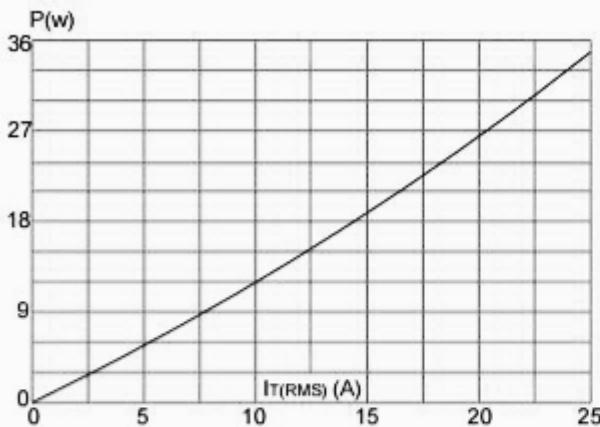
Symbol	Name and test conditions	Quadrant	Range	value		Unit
$I_{GT}$	$V_D=12V$ $R_L=100\Omega$	I II III IV	MAX	I	III	mA
				$\leq 50$	$\leq 120$	
$V_{GT}$	$VD = VDRM$ , $RL = 3.3 k\Omega$ , $T_j = 125^\circ\text{C}$	IV	MAX	1.5		V
$V_{GD}$				0.2		
$I_H$	$I_T=500\text{mA}$		MAX	80		mA
$I_L$	$IG = 1.2 \times IGT$		MAX	80		mA
				100		
$dv/dt$	$VD = 67\% VDRM$ , gate open, $T_j = 125^\circ\text{C}$		MIN	500		V/us
$(dv/dt)_c$	Critical rise rate of commutation voltage $T_j = 150^\circ\text{C}$		MIN	10		V/us

## Static parameters

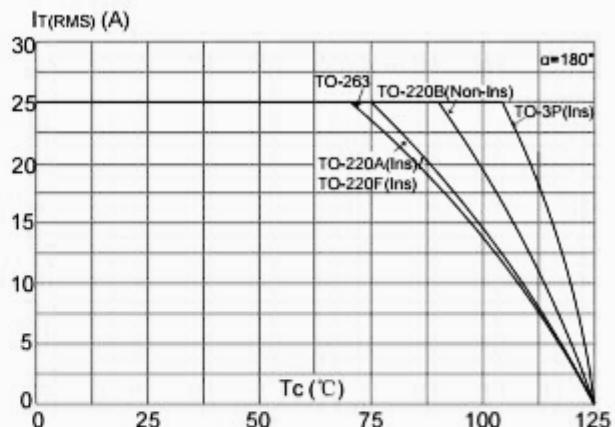
Symbol	Parameter name			value	Unit
$V_{TM}$	$I_{TM}= 50\text{A}$	$T_j=25^\circ\text{C}$	MAX	1.55	V
$V_{T0}$	threshold on-state voltage	$T_j=150^\circ\text{C}$	MAX	0.87	V
$R_d$	Dynamic resistance	$T_j=150^\circ\text{C}$	MAX	14.6	$\text{m}\Omega$
$I_{DRM}$ $I_{RRM}$	$VDRM = VRM$		MAX	5	$\mu\text{A}$
				1	mA
$R_{th(j-c)}$	Junction to ambient	BTA	MAX	2.05	$^\circ\text{C}/\text{W}$

## BTA24 characteristic curve

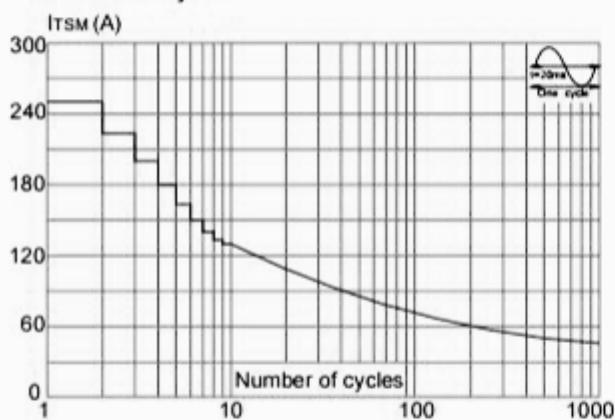
**FIG.1:** Maximum power dissipation versus RMS on-state current



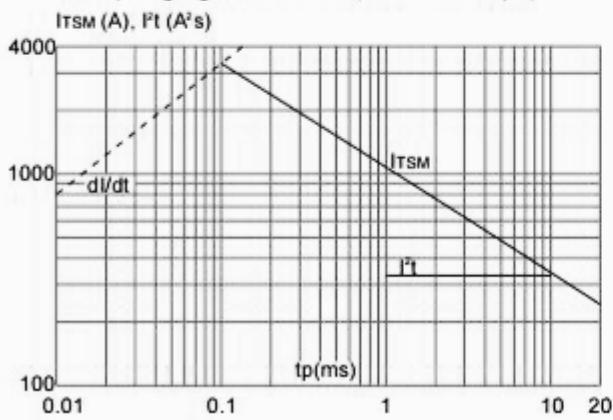
**FIG.2:** RMS on-state current versus case temperature



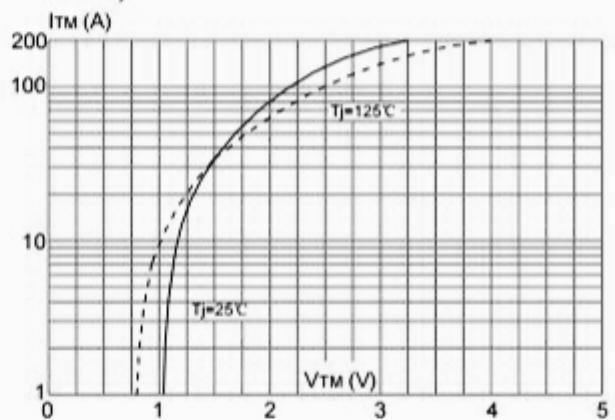
**FIG.3:** Surge peak on-state current versus number of cycles



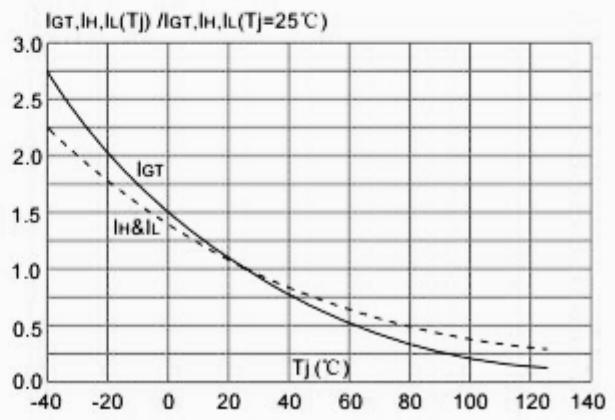
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 50\text{A}/\mu\text{s}$ )



**FIG.4:** On-state characteristics (maximum values)

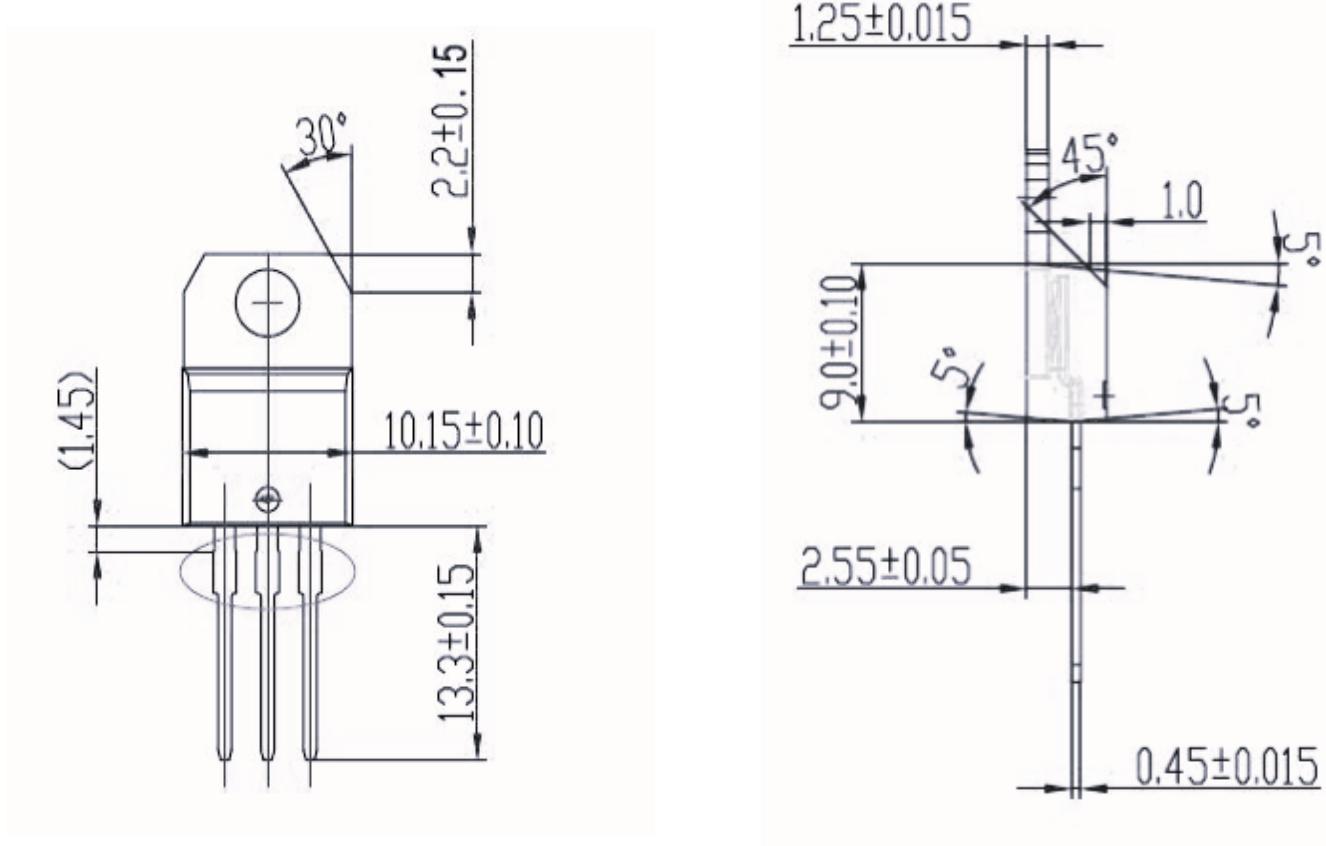


**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



**TO-220A Dimensional drawing:**

Unit: mm ( $\pm 0.1$ )



## Ordering information

Order code	Package	Baseqty	Delivery mode
BTA24-600CRG	TO-220A	1000	Tube and box
BTA24-600BWRG	TO-220A	1000	Tube and box
BTA24-600CWRG	TO-220A	1000	Tube and box
BTA24-800CRG	TO-220A	1000	Tube and box
BTA24-800BRG	TO-220A	1000	Tube and box
BTA24-800BWRG	TO-220A	1000	Tube and box
BTA24-800CWRG	TO-220A	1000	Tube and box